

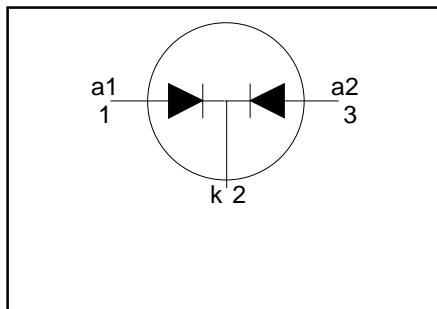
**Rectifier diodes
ultrafast, rugged**

BYV32F, BYV32EX series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$V_R = 150\text{ V} / 200\text{ V}$
$V_F \leq 0.85\text{ V}$
$I_{O(AV)} = 12\text{ A}$
$I_{RRM} = 0.2\text{ A}$
$t_{tr} \leq 25\text{ ns}$

GENERAL DESCRIPTION

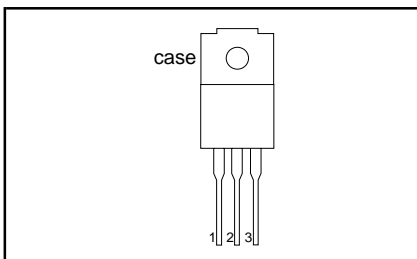
Dual, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV32F series is supplied in the SOT186 package.
The BYV32EX series is supplied in the SOT186A package.

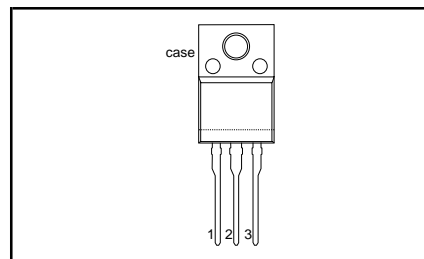
PINNING

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	isolated

SOT186



SOT186A



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
				BYV32F / BYV32EX		
V_{RRM}	Peak repetitive reverse voltage		-	-150	-200	V
V_{RWM}	Crest working reverse voltage		-	150	200	V
V_R	Continuous reverse voltage		-	150	200	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting) ¹	square wave $\delta = 0.5; T_{hs} \leq 95\text{ }^\circ\text{C}$	-	12		A
I_{FRM}	Repetitive peak forward current per diode	$t = 25\text{ }\mu\text{s}; \delta = 0.5;$ $T_{hs} \leq 95\text{ }^\circ\text{C}$	-	20		A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10\text{ ms}$	-	125		A
		$t = 8.3\text{ ms}$	-	137		A
I_{RRM}	Repetitive peak reverse current per diode	sinusoidal; with reapplied $V_{RWM(max)}$ $t_p = 2\text{ }\mu\text{s}; \delta = 0.001$	-	0.2		A
		$t_p = 100\text{ }\mu\text{s}$	-	0.2		A
T_{stg}	Storage temperature		-40	150		$^\circ\text{C}$
T_j	Operating junction temperature		-	150		$^\circ\text{C}$

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_C	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC
 $T_{hs} = 25 \text{ }^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	SOT186A package; $f = 50\text{-}60 \text{ Hz}$; sinusoidal waveform; R.H. $\leq 65\%$; clean and dustfree	-		2500	V
V_{isol}	Repetitive peak voltage from all three terminals to external heatsink	SOT186 package; R.H. $\leq 65\%$; clean and dustfree	-		1500	V
C_{isol}	Capacitance from pin 2 to external heatsink	$f = 1 \text{ MHz}$	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\text{-}hs}$	Thermal resistance junction to heatsink (per diode)	with heatsink compound	-	-	5.0	K/W
$R_{th\ j\text{-}a}$	Thermal resistance junction to ambient	without heatsink compound in free air	-	55	7.0	K/W

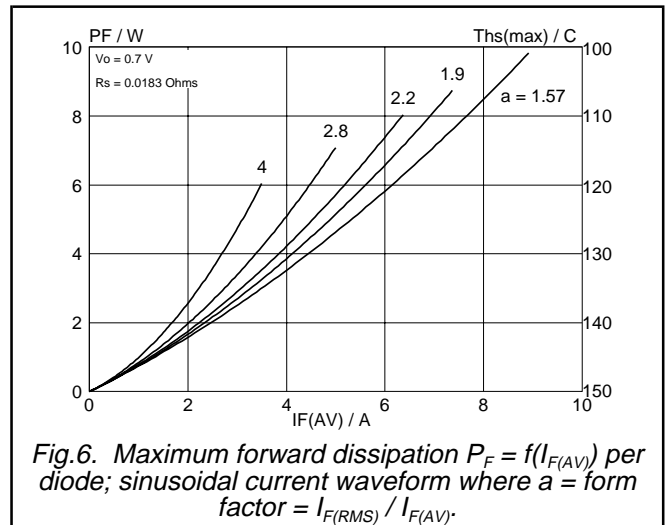
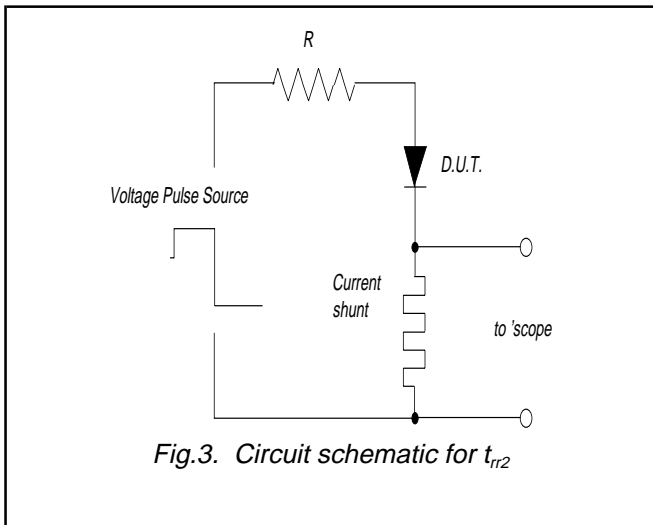
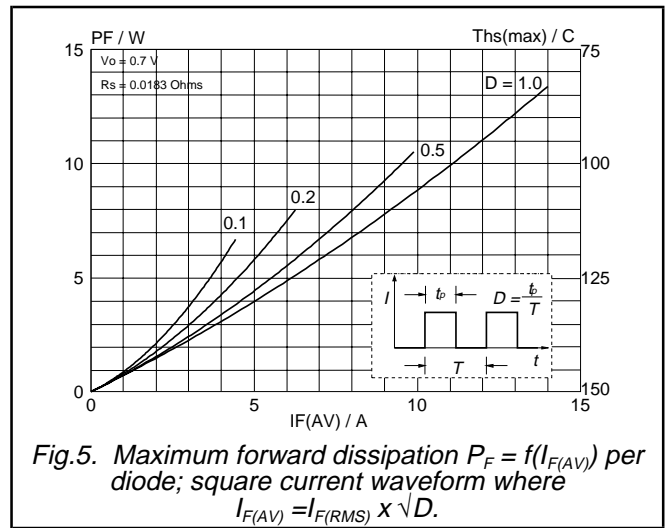
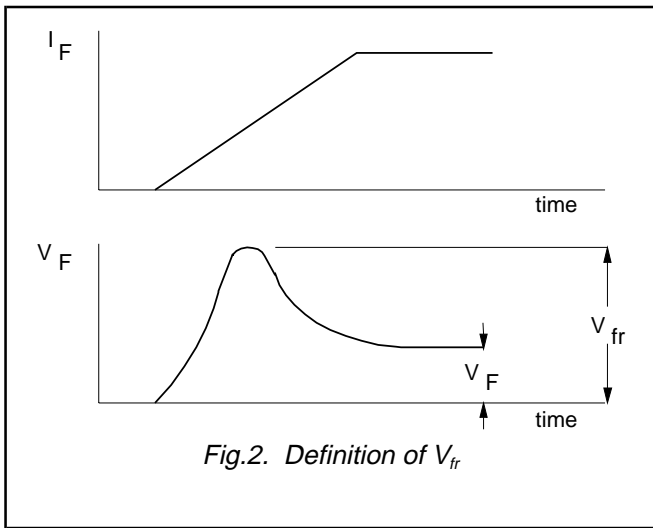
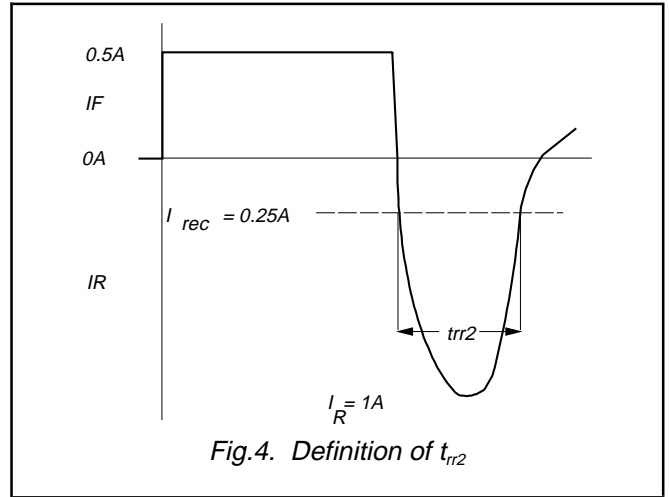
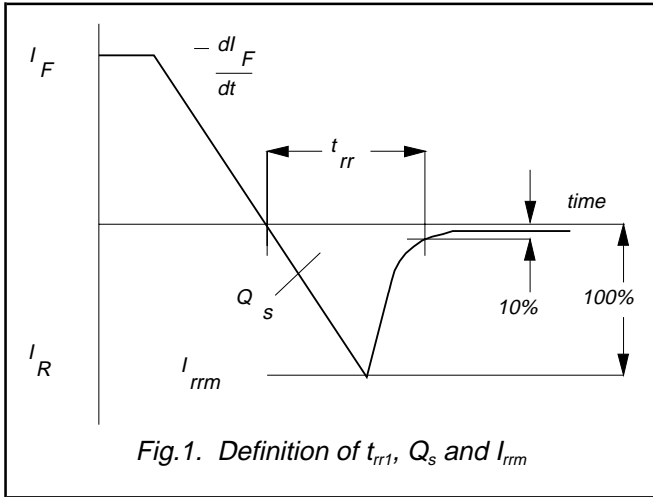
ELECTRICAL CHARACTERISTICS

 characteristics are per diode at $T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 8 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$	-	0.72	0.85	V
I_R	Reverse current	$I_F = 20 \text{ A}$	-	1.00	1.15	V
Q_s	Reverse recovery charge	$V_R = V_{RWM}$; $T_j = 100 \text{ }^\circ\text{C}$	-	0.2	0.6	mA
t_{rr1}	Reverse recovery time	$V_R = V_{RWM}$	-	6	30	μA
t_{rr2}	Reverse recovery time	$I_F = 2 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 20 \text{ A}/\mu\text{s}$	-	8	12.5	nC
I_{rrm}	Peak reverse recovery current	$I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	25	ns
V_{fr}	Forward recovery voltage	$I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; $I_{rec} = 0.25 \text{ A}$	-	10	20	ns
		$I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 50 \text{ A}/\mu\text{s}$; $T_j = 100 \text{ }^\circ\text{C}$	-	1.5	2	A
		$I_F = 1 \text{ A}$; $di_F/dt = 10 \text{ A}/\mu\text{s}$	-	1	-	V

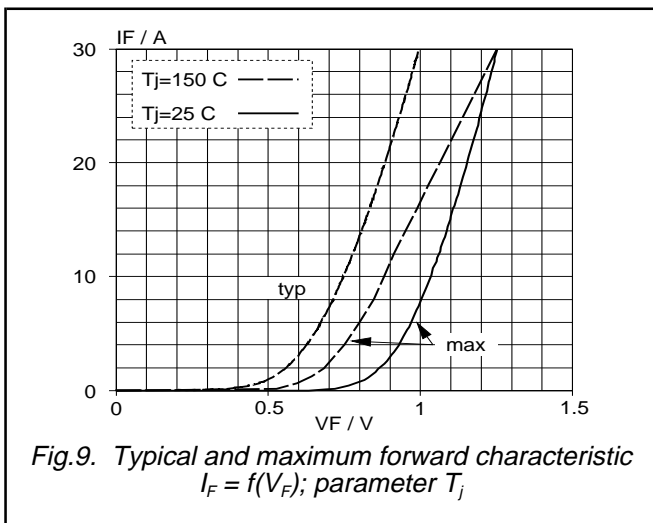
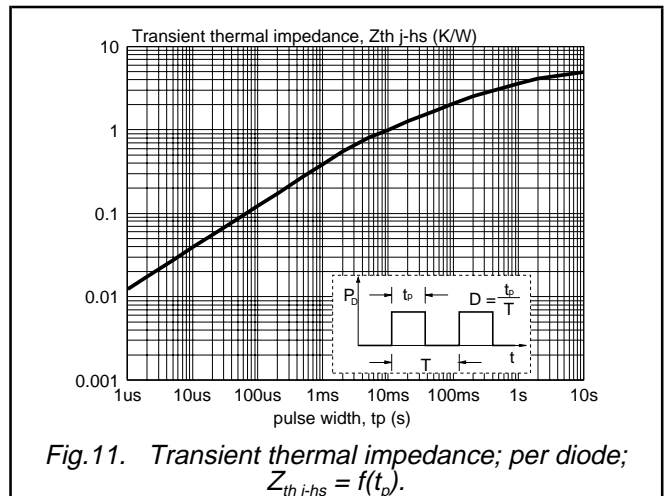
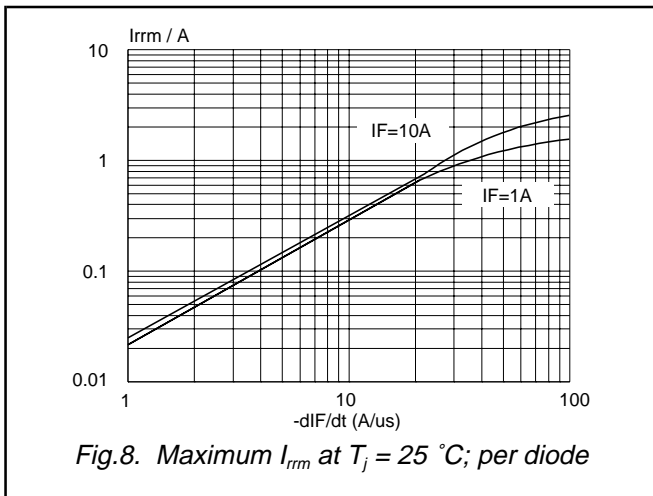
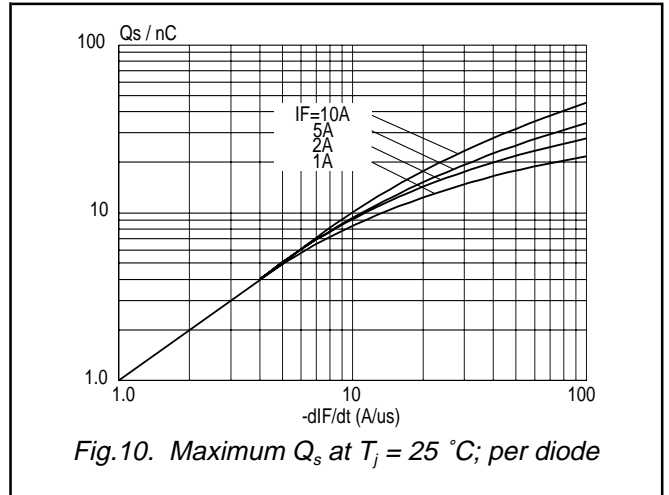
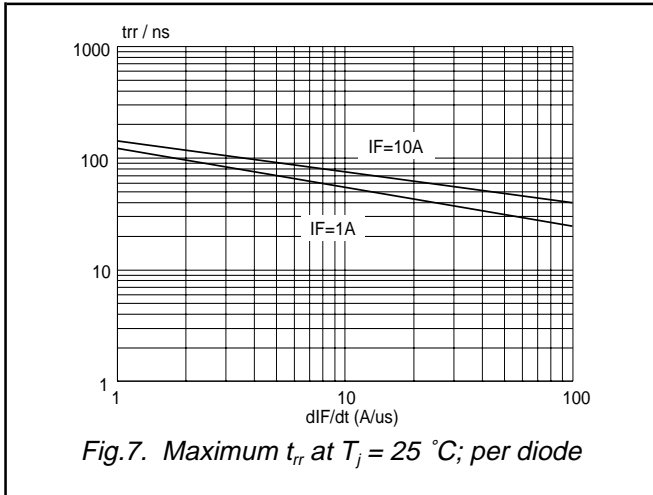
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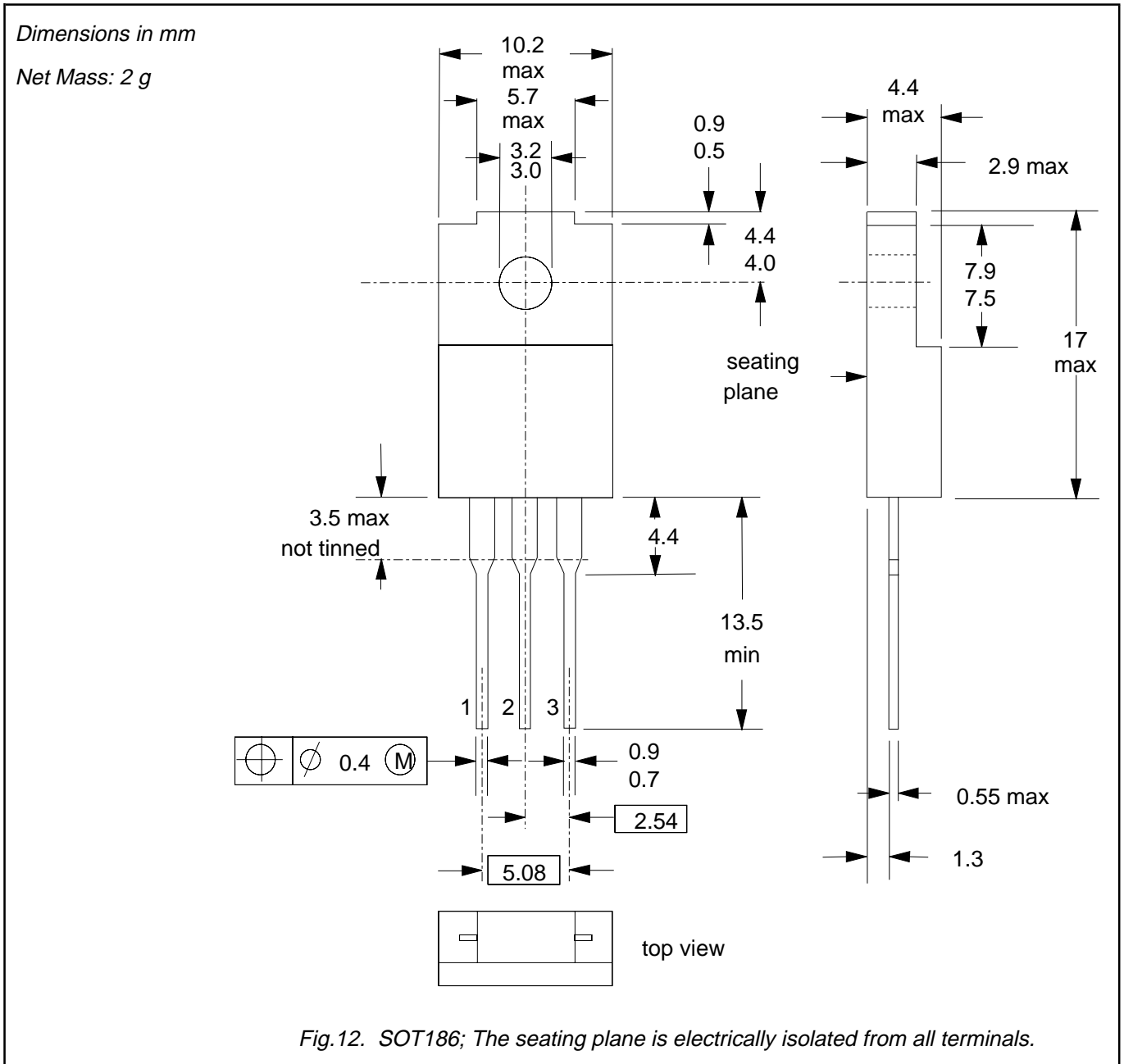
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MECHANICAL DATA



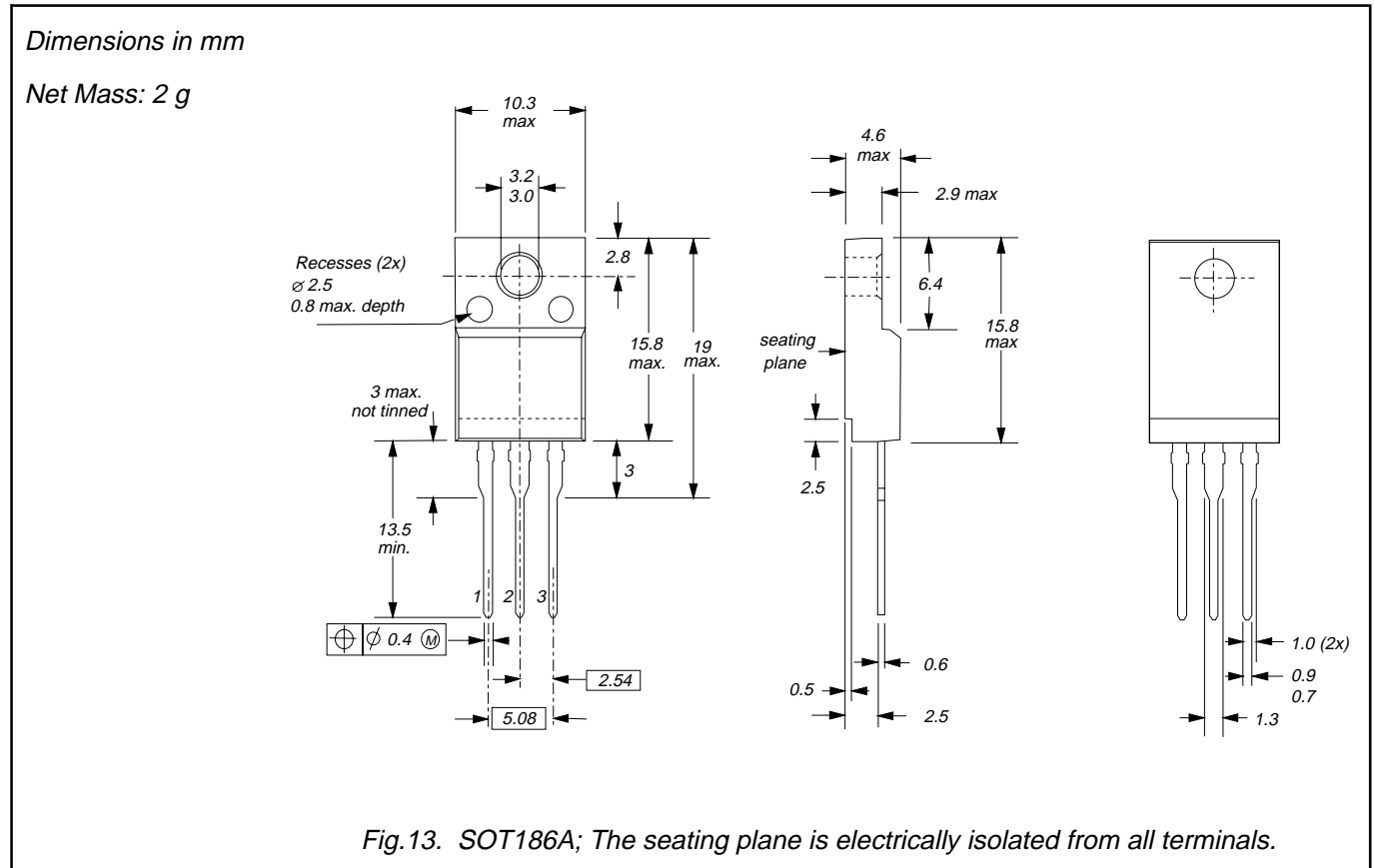
Notes

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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MECHANICAL DATA



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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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